

# 2.0 mm x 2.5 mm Ceramic Package SMD Oscillator, TTL / HC-MOS



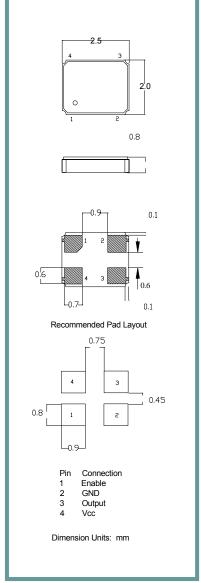
### **Product Features:**

Low Jitter, Non-PLL Based Output CMOS/TTL Compatible Logic Levels Compatible with Leadfree Processing

# **Applications:**

Fibre Channel Server & Storage Sonet /SDH 802.11 / Wifi T1/E1, T3/E3 System Clock

Frequency	1.000 MHz to 60.000 MHz				
Output Level	(0) = 0.4 ) /ac May. (4) = 0.0 ) /ac Min				
HC-MOS TTL	'0' = 0.1 Vcc Max., '1' = 0.9 Vcc Min.				
	'0' = 0.4 VDC Max., '1' = 2.4 VDC Min.				
Duty Cycle	Specify 50% ±10% or ±5% See Table in Part Number Guide				
Rise / Fall Time	5 nS Max. @ Vcc = +3.3 VDC, 10 nS Max. @ Vcc = +5 VDC ***				
Output Load	Fo < 50 MHz = 10 TTL, Fo > 50 MHz = 5 LSTTL See Table in Part Number Guide				
Frequency Stability	See Frequency Stability Table (Includes room temperature tolerance and stability over operating temperature)				
Start-up Time	10 mS Max.				
Enable / Disable Time	100 nS Max. N.C. or ≥ 70% Vdd = Enable. ≤ 30% Vdd = Disable.				
Supply Voltage	See Input Voltage Table, tolerance ±5 %				
Current	25 mA Max. ***				
Operating	See Operating Temperature Table in Part Number Guide				
Storage	-55° C to +125° C				
Jitter: RMS(1sigma) 1 MHz-60 MHz	5 pS RMS (1 sigma) Max. accumulated jitter (20K adjacent periods)				
Max Integrated 1 MHz-60 MHz	1.5 pS RMS (1 sigma -12KHz to 20MHz)				
Max Total Jitter 1 MHz-60 MHz					



Part Number Guide		Sample Part Number:		ISM95 - 3251BH - 20.000			
Package	Input Voltage	Operating Temperature	Symmetry (Duty Cycle)	Output	Stability (in ppm)	Enable / Disable	Frequency
ISM95 -	5 = 5.0 V	1 = 0° C to +70° C	5 = 45 / 55 Max.	1 = 10TTL / 15 pF HC-MOS	**A = ±25	H = Enable	- 20.000 MHz
1011133	3 = 3.3 V	8 = -10° C to +60° C	6 = 40 / 60 Max.	6 = 30 pF	B = ±50	O = N/C	20.000 WII IZ
	7 = 3.0 V	6 = -10° C to +70° C		5 = 50 pF HC-MOS (<40 MHz)	C = ±100		
	2 = 2.7 V	3 = -20° C to +70° C					
	6 = 2.5 V	4 = -30° C to +75° C					
	1 = 1.8 V*	2 = -40° C to +85° C					

NOTE: A 0.01  $\mu$ F bypass capacitor is recommended between Vcc (pin 4) and GND (pin 2) to minimize power supply noise.

<sup>\*</sup> Not available at all frequencies. \*\* Not available for all temperature ranges. \*\*\* Frequency, supply, and load related parameters.

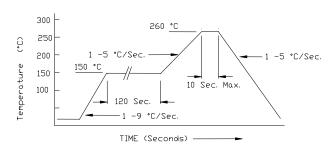


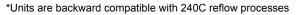


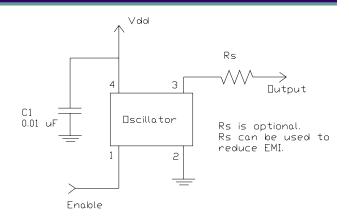
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### **Pb Free Solder Reflow Profile:**

# **Typical Application:**





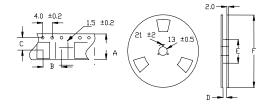


## **Package Information:**

MSL = N.A. (package does not contain plastic, storage life is unlimited under normal room conditions).

Termination = e4 (Au over Ni over W base metalization).

## **Tape and Reel Information:**



Quantity per Reel	1000		
Α	8 +/3		
В	4 +/2		
С	3.5 +/2		
D	9 +/-1 or 12 +/3		
E	60 / 80		
F	180		

## **Environmental Specifications**

Thermal Shock	MIL-STD-883, Method 1011, Condition A
Moisture Resistance	MIL-STD-883, Method 1004
Mechanical Shock	MIL-STD-883, Method 2002, Condition B
Mechanical Vibration	MIL-STD-883, Method 2007, Condition A
Resistance to Soldering Heat	J-STD-020C, Table 5-2 Pb-free devices (except 2 cycles max)
Hazardous Substance	Pb-Free / RoHS / Green Compliant
Solderability	JESD22-B102-D Method 2 (Preconditioning E)
Terminal Strength	MIL-STD-883, Method 2004, Test Condition D
Gross Leak	MIL-STD-883, Method 1014, Condition C
Fine Leak	MIL-STD-883, Method 1014, Condition A2, R1=2x10-8 atm cc/s
Solvent Resistance	MIL-STD-202, Method 215

### Marking

Line 1: ILSI and Date Code (YWW)

Line 2: Frequency